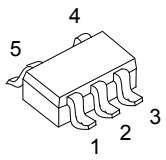
600mA CMOS LDO



SOT-25

■ DESCRIPTION

The UTC **L1186** is a COMS positive linear regulator. One of its features is the very low quiescent current typical as low as 30μA and its dropout voltage is extremely low with 600mA output current.

The internal circuit includes thermal shutdown and current fold-back to prevent device failure when the circuit is operated in the bad conditions.

In application, the UTC **L1186** needs a low noise, regulated supply. For stable operation, the output capacitance value should be 2.2μF or more.

The UTC **L1186** is an ideal for battery applications, such as instrumentations, portable electronics, wireless devices, cordless phones, PC peripherals, and battery powered widgets.

■ FEATURES

* Accurate to within 1.5%
* Quiescent current: 30μA
* Internal over-temperature shutdown
* With current limiting
* Internal short circuit current fold-back
* With noise reduction bypass capacitor
* Has power-saving shutdown mode
* Very low temperature coefficient
* Halogen Free

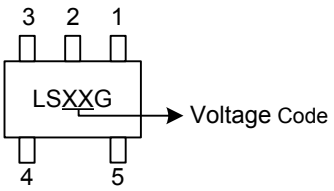
■ ORDERING INFORMATION

Ordering Number	Package	Packing
L1186G-xx-AF5-R	SOT-25	Tape Reel

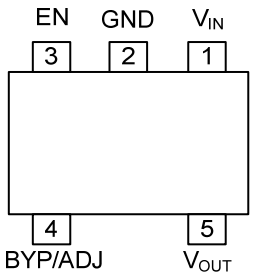
Note: xx: Output Voltage, refer to Marking Information.

L1186G-xx-AF5-R (1)Packing Type (2)Package Type (3)Output Voltage Code (4)Halogen Free	(1) R: Tape Reel (2) AF5: SOT-25 (3) xx: Refer to Marking Information (4) G: Halogen Free

■ MARKING INFORMATION

PACKAGE	VOLTAGE CODE	MARKING
SOT-25	15 :1.5V 28 :2.8V AD:ADJ	

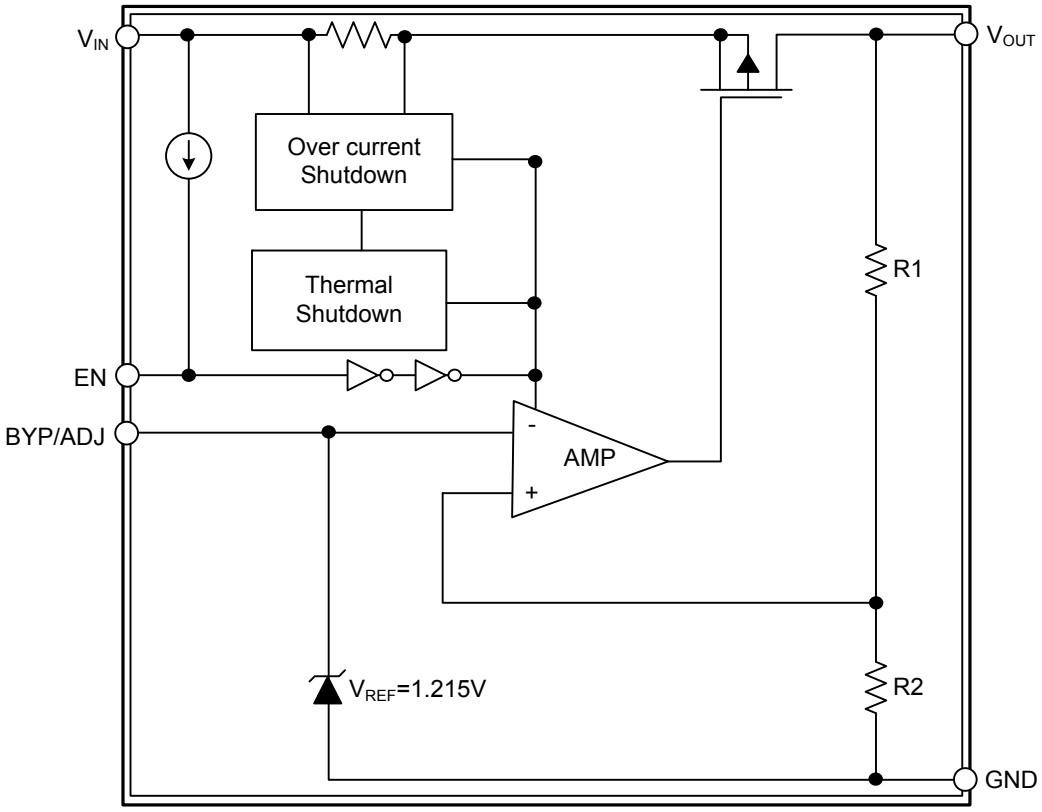
■ PIN CONFIGURATION



■ PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	V_{IN}	Input for voltage input.
2	GND	Ground.
3	EN	Enable pin.
4	BYP/ADJ	Noise Reduction Bypass Capacitor/ Adjusted Voltage
5	V_{OUT}	Output voltage pin

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
Input Voltage	V_{IN}	8	V
Output Voltage	V_{OUT}	GND-0.3 ~ V_{IN}+0.3	V
Output Current	I_{OUT}	$\frac{P_D}{V_{IN}-V_{OUT}}$	A
Power Dissipation	P_D	400	mW
Junction Temperature	T_J	150	°C
Operating Temperature	T_{OPR}	-40~+85	°C
Storage Temperature	T_{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Junction to Ambient	θ_{JA}			260	°C/W
Junction to Case (Note)	θ_{JC}			81	°C/W

Note: θ_{JC} on center of molding compound if IC has on tab

■ ELECTRICAL CHARACTERISTICS (T_a = 25°C, unless otherwise noted.)

Fixed Voltage

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Input Voltage	V_{IN}			Note1		7	V
Output Voltage Accuracy	V_{OUT}	I_{OUT}=1mA		-1.5		1.5	%
Line Regulation	$\frac{\Delta V_{OUT}}{V_{OUT}}$	I_{OUT}=1mA	1.4V<V_{OUT}≤2.0V	-0.15		0.15	%
		V_{IN}=V_{OUT}+1~V_{OUT}+2	2.0V<V_{OUT}<4.0V	-0.1	0.02	0.1	%
Load Regulation	$\frac{\Delta V_{OUT}}{V_{OUT}}$	I_{OUT}=1mA~600 mA			0.2	1	%
Output Current	I_{OUT}	V_{OUT}>1.2V		600			mA
Current Limit	I_{LIMIT}	V_{OUT}>1.2V		600	800		mA
Short Circuit Current	I_{SC}	V_{OUT}<0.8V			300	600	mA
Quiescent Current	I_Q	I_{OUT}=0mA			30	50	μA
Ground Pin Current	I_{GND}	I_{OUT}=1mA~600mA			35		μA
Dropout Voltage	V_D	I_{OUT} =600mA	1.4V<$V_{O(NOM)}$≤2.0V			1400	mV
		V_{OUT}=$V_{O(NOM)}$-2.0%	2.0V<$V_{O(NOM)}$≤2.8V			800	mV
Over Temperature Shutdown	OTS				150		°C
Over Temperature Hysteresis	OTH				30		°C
Temperature Coefficient of Output Voltage	T_CV_O				30		ppm/°C
Power Supply Rejection	PSRR	I_{OUT} =100mA	f=1kHz		75		dB
		C_{OUT}=2.2μF ceramic	f=10kHz		55		dB
		C_{BYP}=0.01μF	f=100kHz		30		dB
Output Voltage Noise	eN	f=10Hz~100kHz, I_{OUT} =10mA C_{OUT}=2.2μF , C_{BYP}=0.1μF			30		μVrms
EN Input Threshold	V_{EH}	V_{IN}=2.7V~7V		2.0		V_{IN}	V
	V_{EL}	V_{IN}=2.7V~7V		0		0.4	V
EN Input Bias Current	I_{EH}	V_{EN}=V_{IN}, V_{IN}=2.7V~7V				0.1	μA
	I_{EL}	V_{EN}=0V, V_{IN}=2.7V~7V				0.5	μA
Shutdown Supply Current	I_{SD}	V_{IN}=5V, V_{OUT} =0V, V_{EN}<V_{EL}			0.5	1	μA
PG Leakage Current	I_{LC}	V_{PG}=7V				1	μA

■ ELECTRICAL CHARACTERISTICS(Cont)

Adjusted Voltage

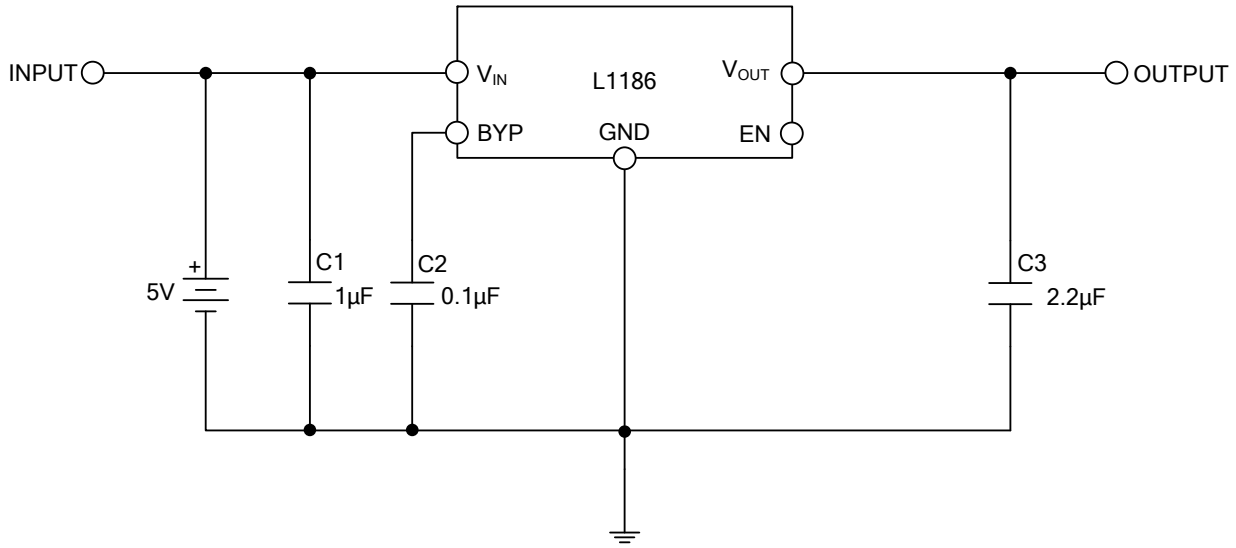
PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Input Voltage	V_{IN}			Note1		7	V
Reference Voltage	V_{REF}			1.196	1.215	1.234	V
Output Voltage Accuracy	V_{OUT}	I_{OUT}=1mA		-1.5		1.5	%
Line Regulation	$\frac{\Delta V_{OUT}}{V_{OUT}}$	$V_{IN}=V_{OUT}+V_D$~7V, I_{OUT}=1mA		-0.15		0.15	%
Load Regulation	$\frac{\Delta V_{OUT}}{V_{OUT}}$	$V_{IN}=V_{OUT}+V_D$, I_{OUT}=1mA~600 mA			0.2	1	%
Output Current	I_{OUT}	V_{OUT}>1.3V		600			mA
Current Limit	I_{LIMIT}	V_{OUT}>1.3V		600	800		mA
Short Circuit Current	I_{SC}	V_{OUT}<0.8V			300	600	mA
Adjusted Current	I_{ADJ}	I_{OUT}=0mA			30	50	μA
Ground Pin Current	I_{GND}	I_{OUT}=1mA~600mA			35		μA
Dropout Voltage	V_D	$V_{OUT}=V_{O(NOM)}$-2.0%, I_{OUT} =600mA				600	mV
Over Temperature Shutdown	OTS				150		°C
Over Temperature Hysteresis	OTH				30		°C
Temperature Coefficient of Output Voltage	T_CV_O				30		ppm/°C
Power Supply Rejection	PSRR	I_{OUT} =100mA C_{OUT}=2.2μF ceramic C_{BYP}=0.01μF	f=1kHz f=10kHz f=100kHz		40 20 15		dB dB dB
Output Voltage Noise	eN	f=10Hz~100kHz, I_{OUT} =10mA C_{OUT}=2.2μF , C_{BYP}=0.1μF			30		μVrms
EN Input Threshold	V_{EH}	V_{IN}=2.7V~7V		2.0		V_{IN}	V
	V_{EL}	V_{IN}=2.7V~7V		0		0.4	V
EN Input Bias Current	I_{EH}	$V_{EN}=V_{IN}$, V_{IN}=2.7V~7V				0.1	μA
	I_{EL}	V_{EN}=0V, V_{IN}=2.7V~7V				0.5	μA
Shutdown Supply Current	I_{SD}	V_{IN}=5V, V_{OUT} =0V, $V_{EN}<V_{EL}$			0.5	1	μA
PG Leakage Current	I_{LC}	V_{PG}=7V				1	μA

Notes: 1. $V_{IN(MIN)}=V_{OUT}+V_D$

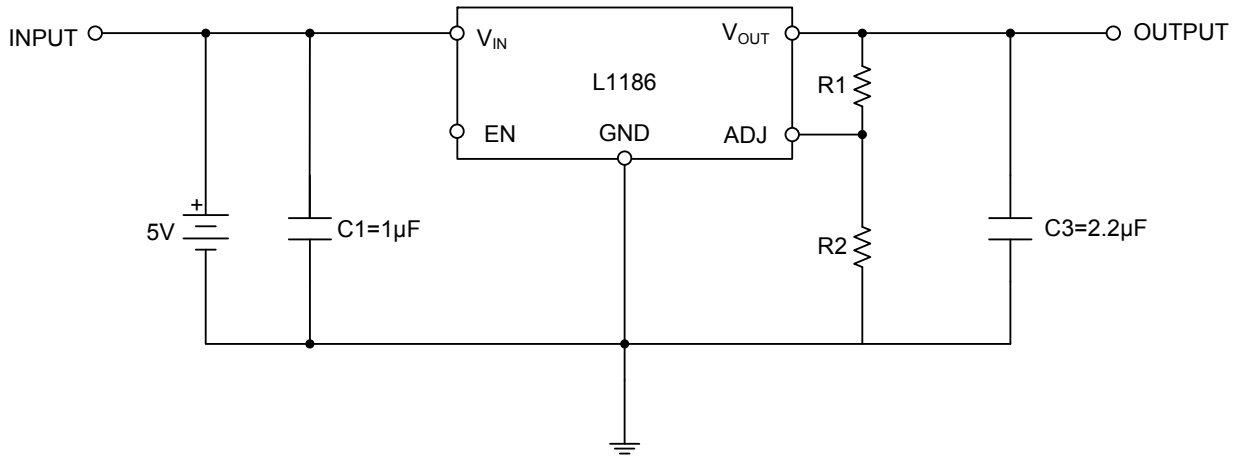
2. To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

■ TYPICAL APPLICATION CIRCUIT

Fixed Voltage



Adjusted Voltage



$$R1 = R2\left[\frac{V_{OUT}}{1.215} - 1\right]$$